TITLE: METHOD OF MAKING A VERTICAL COMPOUND SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE

INVENTOR: Peyman Hadizad DOCKET NO.: ONS00505



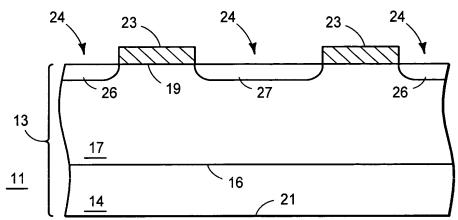


FIG. 1

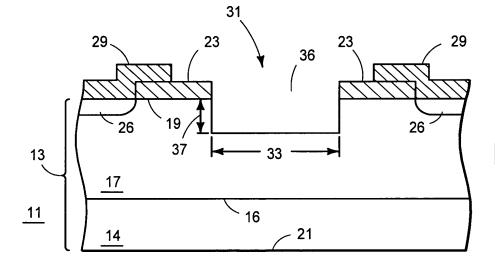


FIG. 2

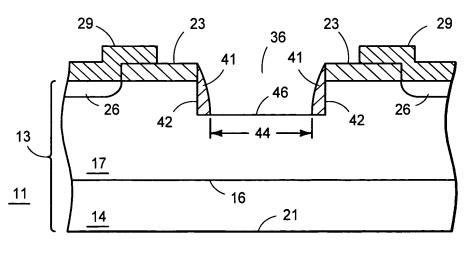
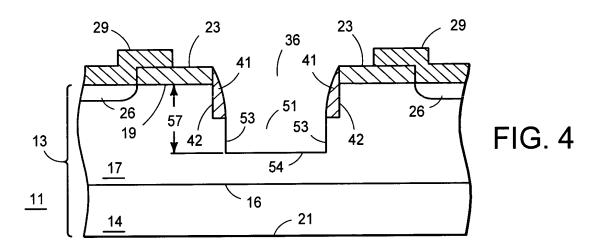
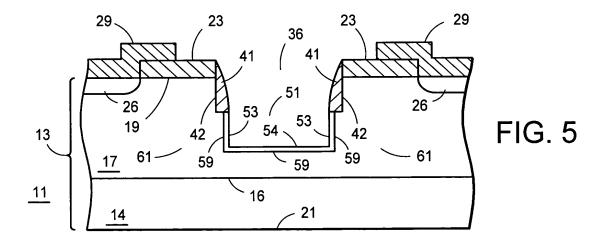


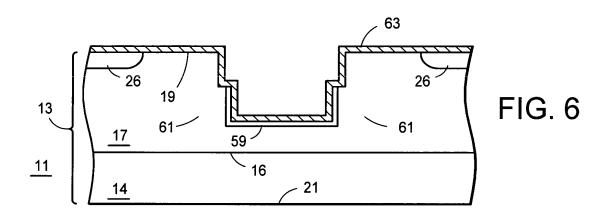
FIG. 3

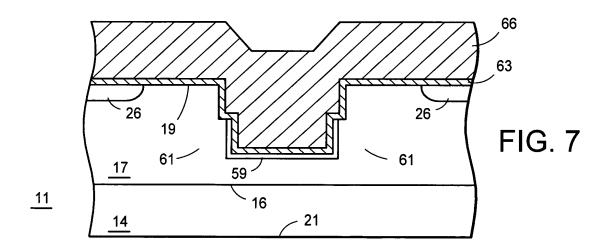
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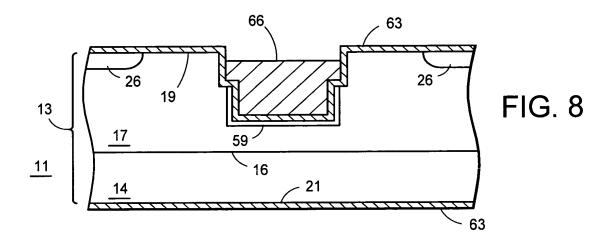


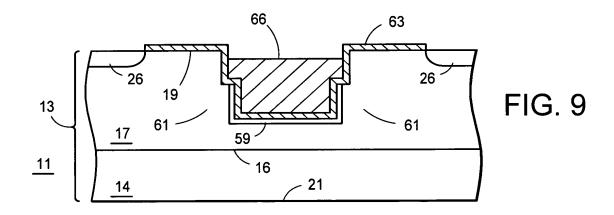


TITLE: METHOD OF MAKING A VERTICAL COMPOUND SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE **INVENTOR: Peyman Hadizad**

DOCKET NO.: ONS00505

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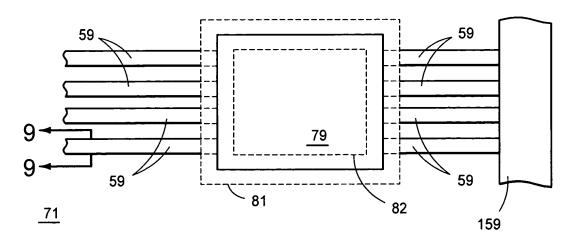


FIG. 10

TITLE: METHOD OF MAKING A VERTICAL COMPOUND SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE INVENTOR: Peyman Hadizad

INVENTOR: Peyman Hadiza DOCKET NO.: ONS00505

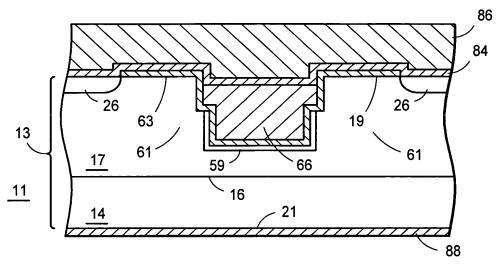


FIG. 11

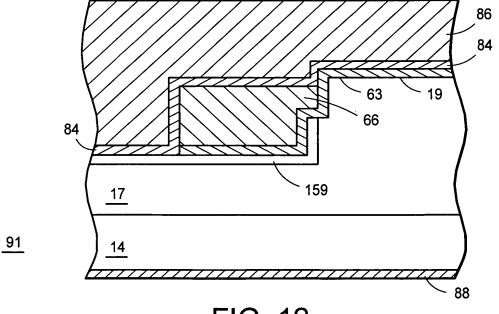


FIG. 12